Density functional theory study of the nem atic-isotropic transition in an hybrid cell

I. Rodr guez-Ponce, J.M. Romero-Enrique, 2,3 and L.F. Rull²

¹Physik Department, Technische Universitat Munchen, James-Franck-Strasse, D-85747 Munich, Germany
²Departamento de F sica Atomica, Molecular y Nuclear, Area de F sica Teorica, Universidad de Sevilla, Apartado de correos 1065, 41080 Sevilla, Spain
³Department of Mathematics, Imperial College 180 Queen's Gate,

London SW 7 2BZ, United Kingdom

Abstract

We have en ployed the Density Functional Theory form alism to investigate the nem atic-isotropic capillary transitions of a nem atogen con ned by walls that favor antagonist orientations to the liquid crystalm olecules (hybrid cell). We analyze the behavior of the capillary transition as a function of the uid-substrate interactions and the pore width. In addition to the usual capillary transition between isotropic-like to nem atic-like states, we nd that this transition can be suppressed when one substrate is wet by the isotropic phase and the other by the nem atic phase. Under this condition the system presents interface-like states which allow to continuously transform the nem atic-like phase to the isotropic-like phase without undergoing a phase transition. Two di erent m echanisms for the disappearance of the capillary transition are identied. When the director of the nem atic-like state is hom ogeneously planar-anchored with respect to the substrates, the capillary transition ends up in a critical point. This scenario is analogous to the observed in Ising m odels when con ned in slit pores with opposing surface elds which have critical wetting transitions. When the nem atic-like state has a linearly distorted director eld, the capillary transition continuously transition s in a transition between two nem atic-like states.

I. IN TRODUCTION

The e ect on con nem ent on simple uids has been vastly investigated in the past. Most of studies are related to the e ect of the con nem ent on the vapor-liquid transition, the socalled capillary transition. In the case of symmetric walls, where both walls attract or repel the molecules with the same strength, the capillary transition in large pores is governed by the well-known Kelvin law¹. In addition, it may appear surface phenom enology that can a ect the global phase diagram. Offen this surface phenom enology is related to wetting states found in the single wall cases. The latter phenom enon is related to the spreading of drops of vapor (liquid) on the surface in coexistence with the bulk liquid (vapor). The presence of these surface states can be considered in the description of the phase behavior in the con ned system . The generalized K elvin law for sm all pores (where surface phenom enology is more dominant) takes into account these e ects so it is still possible to determ ine the vapor-liquid transition for sm all pores². How ever, the predictions of the generalized K elvin law reveal that the wetting phenom ena does not a ect essentially the phase diagram of the con ned problem so they are often discarded. An interesting system is the hybrid cell (also known as asymmetric cell) where one substrate or wall is repulsive and the other attractive (com peting walls). In this case, the wetting properties present in the single wall cases play a crucial role in the determ ination of the critical point in the con ned problem. Here, given a pore width, the coexistence of two phases can only occur for tem peratures below T_w , which corresponds to the total wetting tem perature of the single wall cases^{3,4}.

These studies have elucidated which mechanisms are involved in the surface transitions and how the properties of the substrate can determ ine the phase behavior within the pore. With respect to complex uids like liquid crystal (LC) there is an increasing interest in the understanding of the surface phenom ena due to its crucial role in the advance of the LC technology. For the case of a single wall (sem i-in nite problem) and symmetric pores favoring an speci c orientation on the molecules, theoretical approaches^{5,6,7,8,9,10,11} as well as computer simulations^{12,13,14,15,16} reveal that the interaction wall- uid particle can a ect strongly the ordering not only close to the surface but also far from it. A dditionally to nite size e ects, novel phenom ena often appear due to the combined presence of anchoring and orientational wetting transitions. The interplay between both surface phenom ena and its dependence on wall properties have been recently studied by us employing a microscopic

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Density Functional Theory (DFT) approach for a simple model of liquid crystal¹⁷. The e ect of con nement by symmetric walls on these surface transitions was also studied¹⁸. Our notings revealed that as in the case of simple uids, the nite-size e ects for not very narrow pores on the phase diagram are not of qualitative signi cant in portance and only the location of the capillary transitions are a ected by the con nement. However, recent theoretical^{19,20} and simulation results¹⁹ for hard-spherocylinder models show that for very narrow symmetrical pores the NI capillary transitions may end up in a critical point.

In a recent paper²¹, we extended the study to the case with an hybrid cell where the surfaces favor antagonist orientations. This geometry has in LCs a particular interest due to the possible technological applications. This fact has stimulated an increasing interest by experim entalists and theoreticians^{19,22,23}. In particular, di erent nem atic-like states with hom ogeneous and linearly distorted director elds were found to coexist under connem ent. In the present paper, our goal is to complete this study with the investigation of the new atic-isotropic (N I) transition within the hybrid cell. Quintana et al investigated a sim ilar problem employing a Landau-type theory²⁴. They claim ed that the NI transition either appears una ected and its tem perature $T_{N I}$ remains unchanged or the transition disappears. Basically what determ ined the existence of the transition was the value of uidwall interaction strength with respect to the value for the st-order wetting transition for the sem i-in nite system s. For strength values below this threshold the transition occurs for all wall separations. In contrast, above the threshold, the transition disappears for large pore widths, where interfacial-like states appear. These states are related to the wetting states by isotropic and nem atic phase that each wall present in the sem i-in nite geometry, respectively.

In this paper we address the same problem of the behavior of the NI capillary transition and its possible disappearance from a more microscopic point of view by using a DFT approach. Our paper is organized as follows. First we brie y present our liquid crystalm odel in Section II. In Section III we revisit and complete the study of a substrate which favors either planar or hom eotropic anchoring in contact with a nem atogen uid at its isotropic or nem atic phase. In particular, the di erent wetting regimes are found. This phenom enology will be a crucial guide to understand the behavior of the uid under con nem ent. Section IV is devoted to the study of the uid adsorbed in a hybrid cell, paying special attention to the disappearance of the NI capillary transitions and the mechanism s involved in it. Finally

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we end up with our conclusions.

II. THE MODEL

The theoretical model is a standard generalized van der W aals theory based on a perturbative expansion, using a hard-sphere (HS) uid as reference system ⁷. D etails on the physical basis of the model and how to obtain its solutions numerically can be found elsewhere^{25,26}. O ur starting point is the grand potential functional per unit system area A, []=A, whose functional minimum with respect to the one-particle distribution function, (r;^), which depends on both molecular positions r and orientations ^, gives the equilibrium structure of the interface. This function, (r;^) (z) f (z;), contains a mass distribution (z) and an angular distribution f (z; ^). These quantities vary locally with the distance from z = 0 to z = H, where H is the pore width. The expression for [], in a mean eld approximation is,

$$[] = F_{r}[] + \frac{1}{2} \sum_{ZZ} Z Z drdr^{0}d^{0} (r;) (r^{0};)$$

$$v(r r^{0};) drd^{(r;)} [v_{W} (r;)]; \qquad (1)$$

where is the chem ical potential and

is the reference system free energy. In the above expression f_{hs} ((r)) is the hard-sphere free energy density of a uniform uid with a density equal to the local density at r and h::: is an angular average. The attractive potential v contains anisotropic (dispersion) forces driving the liquid-crystalline behavior of the m odel m aterial:

$$v(r; \hat{r}; \hat{r}^{0}) = v_{A}(r) + v_{B}(r)P_{2}(\hat{r}^{0})$$

$$+ v_{C}(r) P_{2}(\hat{r}) + P_{2}(\hat{r}^{0}\hat{r});$$
(3)

where $\hat{\mathbf{r}} = \mathbf{r} = \mathbf{r}$, and r is the center-ofm ass distance. The functions v_A (r), v_B (r), v_C (r) are the radial contribution to the potential as a result of considering dispersion-type forces. In this work we choose them to have a simple Yukawa form, i.e. $v_i(\mathbf{r}) = _i \exp((_i(\mathbf{r} \ d))) = \mathbf{r}$ for $\mathbf{r} > d$, and $v_i(\mathbf{r}) = 0$ otherwise, where d is the diam eter of a hard sphere. We note that a positive value of $_C$ favors the molecule to orientate parallel to the NI interface

and a negative value favors the perpendicular orientation to NI interface. This anisotropy in the orientational con guration of the nem atic molecules is essential to understand the phenomenology in the problem with the walls.

The walls are modelled via the following potentials:

$$v_{W}^{1}(z;) = \begin{cases} \overset{\circ}{\geq} +1 & z < 0 \\ \vdots & \vdots \\ & \vdots \\ & & W \end{pmatrix} (z \circ d) P_{2}(\cos z) = 0 \end{cases}$$
(4)

where is the angle between the molecule axis and the z-axis normal to the substrate. For $\frac{1}{W} > 0$, this potential favors the molecules to align perpendicularly to the surface (norm extropic anchoring). The potential corresponding to the other substrate is:

$$v_{W}^{2}(z;) = \begin{cases} \overset{\circ}{\underset{W}{\geq}} + 1 & z > H \\ \vdots & \vdots & z > H \\ \vdots & \vdots & y = w \quad (H = z) \quad d \end{pmatrix} P_{2}(\cos z) \quad z < H \end{cases}$$
(5)

which favors the molecules to align in a plane parallel to the surface for $\frac{2}{W} > 0$. However, this preferred alignment corresponds to a random planar anchoring, since there is not a preferred direction at the xy orientation plane. The parameters $\frac{1}{W}$ and $\frac{2}{W}$ measure the substrate-uid interaction strength of each substrate.

In our study, we will assume that the nem atic director orientation is embedded in the xz plane. The form alism perm its to de ne the orientation distribution of the molecules referred to a laboratory reference system, described by three order parameters,

$$(z) = d \sin d f(z_i) P_2(\cos z)$$
(6)

$$(z) = d \sin d f(z; \hat{j}) \sin 2 \cos$$
(7)

$$(z) = d \sin d f(z_i) \sin^2 \cos 2 \qquad (8)$$

The order also can be referred to an intrinsic reference system by three quantities: the tilt angle de ned like the angle form ed by the director with the z axis, U (uniaxial order param eter) the amount of order along the director and B (biaxial order param eter) which m easures the amount of order along the perpendicular directions of the director. The nem atic ordering is essentially uniaxial (B = 0) far from the substrate. The biaxiality induced by the surfaces was already discussed in a previous paper²¹.

These intrinsic order parameters can be obtained in terms of the set f ; ; g by the following expressions,

S

$$\tan (z) = \frac{r}{(z)} \frac{(z)}{2} + (z) \frac{(z)}{2} + (z)^{2}$$
(9)

$$U(z) = \frac{(z)}{4} + \frac{3}{8}(z) + \frac{3}{4}(z) - \frac{(z)}{2}^{2} + (z)^{2}$$
(10)

B (z) =
$$\frac{(z)}{2} + \frac{3}{4}$$
 (z) $\frac{1}{2}$ (z) $\frac{(z)}{2}^2 + (z)^2$ (11)

It is convenient to de ne the average density and order parameter for the con ned system as:

$$=\frac{1}{H} \int_{Z_{0}}^{Z_{H}} (z) dz$$
 (12)

$$U = \frac{1}{H} \int_{0}^{L} U(z) dz$$
 (13)

As we will also make reference to the sem i-in nite problems, the adsorption in the order parameter is de ned as:

$$= (U \quad U_{\rm b})dz \tag{14}$$

where U_b is the value of the intrinsic nem atic order parameter of the bulk phase.

Numerical values for the potential parameters were taken as $_{\rm A} = 1$ (which sets the temperature scale), $_{\rm B} = _{\rm A} = 0.847$ and $_{\rm C} = _{\rm A} = 0.75$. The range parameters $_{\rm i}$ are set, in units of d (throughout we choose this unit to set the length scale), to $_{\rm i} = 2;4;1:75$, i = A;B;C respectively, and $_{\rm W} = 1$. In our calculations the temperature is xed at the value T $k_{\rm B}T = _{\rm A} = 0.57$, that corresponds to a typical situation in which vapor, isotropic and nem atic phases can be observed. At this temperature, the isotropic-nem atic coexistence occurs for a reduced chem ical potential $=k_{\rm B}T = 3.918$.

III. THE SEM I-INFINITE CASE.

In order to better understanding the behavior of the uid inside the pore, we have rst considered the sem i-in nite cases of the uid in presence of a single substrate that either favors hom eotropic or planar alignment, i.e. the substrate-uid interaction potentials are given by Eq. (4) with $\frac{1}{W} > 0$ or $\frac{1}{W} < 0$, respectively. We are interested in the wetting behavior, so the system will be at bulk nem atic-isotropic coexistence, unless stated otherwise. We have considered both situations in which the bulk uid is either isotropic or nem atic.

First we consider the case of a nem atic bulk phase in presence of the substrate. This situation was studied for substrates that favor hom eotropic anchoring in Ref. 17. We extend this analysis to substrates which favorplanaralignment. For both negative and sm all positive values of $\frac{1}{M}$ the uid far from the substrate orientates parallel to the substrate. For the case in which $\frac{1}{W} < 0$, biaxiality is developed in a microscopic layer close to the substrate, leading to the decay of the orientational order in that area. If the substrate favors a hom eotropic alignment, we observe a microscopic isotropic-like layer close to the substrate, corresponding to a partial wetting situation of the substrate nem atic interface by the isotropic phase. A s $\frac{1}{10}$ is increased, the isotropic layer close to the substrate becom es m acroscopic as the isotropic phase completely wets the nem atic-substrate interface at $\frac{1}{W} = \frac{W^1}{W}$. Our calculations showed that the wetting transition is continuous. The orientation far from the substrate remains planar in the complete wetting case. By further increasing $\frac{1}{W}$, an anchoring transition occurs for $\frac{1}{W} = \frac{d}{W}$, as the nem atic orientation changes from planar to hom eotropic far from the substrate, and the wetting becom es partial again since the isotropic-nem atic interface favors a planar anchoring in our model. The anchoring transition is rst order and continues in the single nem atic phase region. However, the complete wetting with planar orientation state remains metastable up to $\frac{m}{w}$. This fact will be important for the discussion of the conned cases. For the model parameters considered in this paper, $W^{1} = A = 0.470$, $W^{d} = A = 0.527$ and $_{W}^{m} = _{A} = 0:72$.

We turn to the case in which there is an isotropic phase in bulk. For small values of j_W^1 j the inhomogeneities of the density and order parameter proles are restricted to a microscopic layer close to the substrate. A lithough the uid is isotropic far from the substrate, the anisotropic character of the substrate-uid potential induces a random planar ordering near the substrate, i.e. the particles orientate parallel to the substrate but without any preferred direction in that orientation plane (< 0, = = 0). Such a condition can be seen as an extrem e biaxial case, where B = 2U, i.e. the highest eigenvalue of the orientational order parameter tensor is twofold degenerate. The layer width remainsmicroscopically nite as the N I coexistence is approached, corresponding to a partial wetting situation. For large enough values of j_W^1 j, we observe complete wetting situations. For negative values of $\frac{1}{W}$ and

at the N I coexistence, there is a sudden change at $\frac{1}{W} = \frac{w^2}{W}$ from the previous surface state to a complete wetting state of the isotropic-substrate interface by the nem atic phase. This corresponds to a rst order wetting transition. For our model parameters, $W^{2} = A = 0.359$. Due to its rst order character, there is a prew etting rst-order transition for $_{\rm W}$ < $_{\rm W}^{\rm W^2}$ (see Fig. 1). At this transition the particles at the st layer orientates along som e direction parallel to the substrate, breaking the rotational symmetry of the state (see insets of Fig. 1 for the order parameter pro les). Consequently, the prevetting transition can be seen as a two-dimensional isotropic to nem atic transition at the uid layer close to the substrate. We will denote I and $I^{\mathbb{N}}$ to the surface states with the random planar and nem atic layer close to the wall, respectively. For the $I^{\mathbb{N}}$ state, there is also biaxiality near the substrate, as occurred when there was a nem atic uid in bulk. A similar behavior was found for the Zwanzig model and hard spherocylinder uids¹⁹, although their \prewetting" transition is continuous (second order for the Zwanzig m odel and it is expected to be K osterlitz-T houlesslike for the spherocylinder system). The prewetting surface new atization transition shifts towards lower chem ical potentials as $_{W}$ is increased, and eventually disappears at a critical point.

For large positive values of $\frac{1}{W}$, i.e. $\frac{1}{W} = \frac{1}{A} > \frac{W^{3}}{W^{3}} = \frac{1}{A} = 0.691$, we also found that the nem atic phase com pletely wets the isotropic-substrate interface. We have checked indirectly this by studying the num erically obtained pro les that m inim ize our free energy functional. The order parameter proles that we obtain in our num erical minimization are inhom ogeneous along the wetting layer (see Fig. 2). This fact is due to the m ism atch of anchoring conditions at the interfaces. We st note that the intrinsic order parameters are hom ogeneous along the wetting layer except close to the interfaces (see inset in Fig. 2). So the origin of the inhom ogeneity of the extrinsic order parameters is the change of the orientation of the new atic director eld along the wetting layer. As previously mentioned, the molecules align parallel to the interface between a nem atic and isotropic phase. On the other hand, the m olecules anchor hom cotropically close to the substrate due to the strong anchoring coupling between the substrate and the uid. As the nem atic layer width diverges, it is possible to ful llboth anchoring conditions by slow ly varying the nem atic director from hom eotropic to planar anchoring. However, any num erical calculation requires m in im ization in a nite range R for the z coordinate, in posing bulk isotropic conditions for z > R. In this situation, the nem atic director pro le that corresponds to the minimum of the grand-canonical free

energy is expected to be linear, as it is indeed observed by numerical minimization (see inset of Fig. 2). This fact induces a 1=R dependence of the apparent equilibrium excess grand-canonical free energy (or surface tension) due to the elastic deformation. Such decay is much slower than the usual exponential correction when elastic deformations are not involved, and we have to consider much larger values of R to obtain reliable values of the true equilibrium free energies. As R increases, the apparent surface tension decreases and it is always larger than the complete wetting state excess free energy, that it is the sum of the surface tension $_{WN}$ corresponding to the interface between substrate and a nematic phase oriented hom eotropically far away, and the surface tension $_{N I}$ between corresponding to the nematic-isotropic interface where the nematic phase is planar-anchored with respect to the interface. The latter surface tension is independent of the uid-substrate interactions, and its value is $_{N I} d^2 = 0.0259$ for the N I coexistence at T = 0.57.

Fig. 3 sum marizes the results of this Section. We represent the cosine of the contact angle of a droplet of isotropic phase in coexistence with bulk the nem atic phase on a planar substrate as a function of $_{\rm W}$. The Young equation states that:

$$\cos = \frac{wN \quad wI}{NI}$$
(15)

where $_{WN}$, $_{WI}$ and $_{NI}$ are the surface tensions corresponding to the substrate-nem atic, substrate-isotropic and nem atic-isotropic interfaces, respectively. For $_{W}$ < $_{W}^{d}$ (including negative values), the nem atic director is parallel to the substrate far from the substrate. O therw ise, the nem atic director is hom eotropically anchored. The complete wetting region corresponds to $\cos = 1$. The curve meets the $\cos = 1$ line at $_{W} = _{W}^{W1}$ with no change in slope. This fact is a signature of the second-order character of the wetting transition. O n the contrary, the curve departs from the $\cos = 1$ line at $_{W} = _{W}^{d}$ with non-zero slope, indicating the rst-order character of the dewetting transition.

Fig. 3 also gives inform ation about the wetting properties when there is an isotropic phase in bulk. By reversing the roles of the nem atic and isotropic phases in Eq. (15), it is straightforward to see that the contact angle ⁰ of a nem atic droplet on a planar substrate is related to via ⁰ = . Consequently, when $\cos = 1$ we observe complete wetting by nem atic phase of the isotropic-substrate interface. This fact is clear for $_{\rm W} < _{\rm W}^{w2} < 0$. However, for $> _{\rm W}^{w3}$ the apparent values of \cos are less than 1. A spreviously discussed, this is a nite-size e ect of our num erical calculations and the predicted value is $\cos = 1$.

Nevertheless, since the nem atic layer remains nite as $_{W}$! $_{W}^{W^{3}}$ from below, the localization of the wetting transition is quite accurate. For both wetting transitions at $_{W}^{W^{2}}$ and $_{W}^{W^{3}}$ there is a change of slope of the cos curve, that it is in agreement with their rst-order character.

IV. THE CONFINED CASE.

We turn to the case of the uid con ned in a hybrid slit pore, where each substrate favors an antagonist anchoring, i.e. how eotropic and planar, respectively. Under con new ent, it is well known that the bulk transitions have lower-dimensional counterparts that are known as capillary transitions. The therm odynam ic conditions (temperature, pressure, chem ical potential) for such transitions are usually shifted with respect to the bulk coexistence values. Before considering our DFT results, we consider the predictions of the K elvin equation, which gives the leading order for the shift on chem ical potential $= {}_{N I} {}_{N I} {}_{N I}$ of the capillary nem atic-isotropic transition ${}_{N I}^{c}$ with respect to the bulk value ${}_{N I}^{b}$ at large pore widths H. Therm odynam ic considerations^{2,20,27} show that the chem ical potential shift of a capillary transition with respect to the bulk one between the and phases at a given tem perature obeys asymptotically:

$$\frac{(\cos_1 + \cos_2)}{()}$$
(16)

In this expression, is the surface tension for an interface, and and are the bulk densities of the and phases, respectively. Finally, $_1$ and $_2$ are the contact angles corresponding to the droplets of phase that nucleate on each substrate when the uid is in bulk in the phase, respectively. In our case, we can identify as the isotropic phase and as the nem atic phase. It is implicitely assumed in Eq. (16) that there is a partial wetting situation for both substrates in sem i-in nite geometries. However, if either there is complete wetting only at one substrate or in both but by the same phase ($_1 = _2 = 0$ or

), the elective pore width in Eq. (16) is reduced to H l, where is a constant that depends on the range of the wall-uid interactions and l is the sum of the widths of the adsorbed wetting layers. Nevertheless, this modi cation does not change qualitatively the results. Its only elect is to observe the behavior predicted by the Kelvin equation at larger values of the pore width H than for a partial wetting situation.

A di erent situation arises when both substrates are com pletely wet by di erent phases at

coexistence, i.e. $\cos_1 \cos_2 = 1$. Studies for symmetrically opposing surface elds Ising system s^{3,4} and Landau-de Gennes models of liquid crystals²⁴ show that in this situation there is no capillary transition. Instead, an interface-like state appears, where half the pore is led with an -like layer, and the rest by -like phase. The position of the interface between both layers is controlled by the deviation of chemical potential with respect to the coexistence value, being possible to go from an -like capillary pure phase to a -like one without undergoing any phase transition. The phase transition is only recovered in the bulk lim it H = 1 . When the opposing surface elds are not symmetrical (at least for near-symmetrical), it is expected to observe a similar behavior³.

This analysis allow s us to envisage di erent scenarios for the con-ned case and large H. For simplicity, we will only consider the case $\frac{1}{W} = \frac{2}{W}$ w in Eqs. (4) and (5). We must note that this choice does not correspond to the symmetrical opposing elds, since the e ect of each substrate is qualitatively di erent. For large H and $_{W} = _{A} < 0.48$ and $_{W} = _{A} > 0.53$ we expect to have a nem atic-isotropic capillary transition. The transition point will shifted towards lower or higher chem ical potentials than the corresponding to the bulk transition if cos $_{1}$ + cos $_{2}$ is negative or positive, respectively. This state-dependent capillary transition shift, which does not occur for simple uids, has been observed in ourm odel under con nem ent between symmetrical substrates that favor hom eotropic anchoring¹⁸, and also in con-ned spherocylinder model with the Onsager approximation for a symmetrical slit pore²⁰. On the other hand, if 0.48 < $_{W} = _{A} < 0.53$, no capillary transition is expected to be obtained for any pore width.

We present now our DFT calculations. For the sake of clarity, we separate the results obtained for $_{W} < _{W}^{w1}$ and $_{W} > _{W}^{d}$.

A. The case $W < \frac{W^1}{W}$

W e perform ed our rst DFT calculations for $_{W} = _{A} = 0.30$, which correspond to partial wetting situation in the sem i-in nite geom etry for both substrates. Fig. 4 shows the behavior of the averaged intrinsic order parameter U as the chem ical potential is varied. W e see that there is a transition from an isotropic-like state (low er branch) to a nem atic-like state (upper branch). The order of the transition is rst-order, and it is found as the coincidence point of the grand-canonical free energies of the nem atic-like and isotropic-like states. W e have

shown also the metastable continuations of each branch: nem atic-like states on the left of the capillary NI transition and isotropic-like states on the right of the transition. Exam ination of the order parameter proles show that the director eld in the nem atic-like state is oriented parallel throughout the pore to the substrate with an intrinsic order parameter sim ilar to the bulk value, except in thin layers around the substrates, where the density and order parameter pro les are similar to the ones corresponding to the semi-in nite cases. In particular a very thin layer close to the z = 0 substrate is hom eotropically anchored. This state corresponds to the S state in Ref. 21 and we will denote it by N ^S. On the other hand, the isotropic-like state (which we will denote as I) develops m icroscopic hom cotropically and random -planar layers close to the z = 0 and z = H substrates, respectively, and the orientational ordering decays to zero in the middle region of the pore. We have also compared our DFT calculations with the Kelvin law prediction Eq. (16) (see inset in Fig. 4). A lthough the transition value departs from this prediction for sm all pore widths, for H =d > 20 the agreem ent between our num erical estim ations and the K elvin predicted value is quite reasonable. Note that the capillary NI transition is shifted to larger chem ical potentials than the bulk N I transition value. How ever, as w increases, this trend is reversed (the K elvin law predicts the turning point to occur at $_{W} = _{A} = 0.329$).

As $_{W}$ exceeds $_{W}^{w2}$, wetting in the z = H wall begins to a lect the pore adsorption. For small values of H a single transition between an isotropic-like I state to a nem atic-like state occurs as for $_{W} < _{W}^{w2}$. However, as H increases the order of the \nem atic-like" state decreases and the chemical potential for which this transition occurs converges to the I I^N transition value for the z = H wall. The order-parameter proles make clear that the \nem atic-like" state corresponds to the form ation of a nem atic layer close to the z = H substrate followed by an isotropic ordering along the pore. By analogy with the sem i-in nite situation, we call I^N to the con ned state after this transition, which we can see as a rem iniscence of the I I^N transition in the sem i-in nite phenom enology.

As H increases, in addition to the I I^N transition, a new phase transition between the I^N to a proper nem atic-like state N^S (i.e. planar-anchored along the pore) is observed. This transition can be regarded as the true capillary N I transition. Fig. 5 shows our D FT calculations for H = 20d and di erent values of $_M$. It becomes clear that the di erence between the I^N and the N^S states at the transition decreases as $_M$ increases, and eventually the N I capillary transition disappears in a critical point (see inset of Fig. 5). The value of w at which the N I capillary transition disappears is lower than W^{1} , i.e. the con nem ent distabilizes the two-phase region with respect to the one-phase region. We have also studied the elect of the pore width in the N I capillary transition. We set W = A = 0.465, slightly below W^{1} . Fig. 6 shows that the capillary N I transition does not exist for the smallest values of H and reappears for H > 50d.

The disappearance of the N I capillar transition shown by our model is not related to the critical points observed for small values of H in other models^{19,20}. A ctually, those cases correspond to symmetrical slit-pores and consequently their phenomenology is not related to wetting properties of the substrates. In our model the N I capillary transition occurs at least for H > 20d when the substrates at z = 0 and z = H are the sam e^{18} . However we cannot rule out the possibility of critical points for very small H, but we will not consider them since the predictions of our model are not reliable in that regime.

Our DFT results about the existence of the NI capillary transition show the opposite trend to the one predicted by a Landau-de Gennes model in Ref. 24, which predicted that the con nem ent stabilized the two-phase region with respect to the one-phase region. M oreover for large values of H the boundary for the non-existence region of the capillary transition was a triple point rather than a critical point. A ctually the scenario shown by our DFT calculations is consistent with the phenom enology that presents a con ned Ising model with opposing surface elds when the wetting transition is critical³. This analogy can be explained heuristically. For large H and $_{W}$ close to $_{W}^{W1}$, the typical con guration close to bulk coexistence corresponds to an interfacial state form ed by an isotropic layer around the z = 0 and a nem atic layer around the z = H wall. In rst approximation the NI interface position is given by them in im um binding potential which is the superposition of the contributions from the two sem i-in nite system s³. As there is a complete wetting situation at the z = H substrate, we can consider its binding potential as a exponentially decreasing function of the interfacial position with respect to the z = H wall cexp[(H $1) = {0 \atop h}$ where c > 0 and $\frac{0}{b}$ is the new atic phase correlation length at bulk NI coexistence. Note that the local minimum corresponding to the bounded state, if any, plays no role in our argum ent as soon as we are far enough from the rst-order wetting transition corresponding to the sem i-in nite case with the z = H wall. On the other hand, the binding potential corresponding to the z = 0 substrate takes the usual form $a \exp(\frac{b}{b}) + b \exp(\frac{2b}{b})$, where a $/ \underset{W}{\overset{W1}{}} > 0$, b > 0 and b is the isotropic phase correlation length at bulk

N I coexistence. So, the complete binding potential for the N I interface, up to irrelevant constants, is:

W (1) = h (H 1) ae
$$\frac{1}{b}$$
 + be $\frac{21}{b}$ + ce $\frac{H}{b}$ (17)

where h / . A critical point must verify:

$$h = \frac{a}{b} e^{\frac{1}{b}} \frac{2b}{b} e^{\frac{21}{b}} + \frac{c}{0} e^{\frac{H}{b}} e^{\frac{1}{b}}$$
(18)

$$0 = \frac{a}{\frac{2}{b}}e^{\frac{1}{b}} + \frac{4b}{\frac{2}{b}}e^{\frac{21}{b}} + \frac{C}{(\frac{0}{b})^2}e^{\frac{H-1}{b}}$$
(19)

Instead of solving simultaneously Eqs. (18) and (19), we will study the spinodal line, which is the solution of Eq. (19). We consider solutions of the form 1 + 1, where 0 < 1 and $1 = \frac{1}{b}$; $\frac{0}{b}$. Substituting this ansatz in Eq. (19), we obtain

$$0 = ae^{\frac{H}{b}} e^{\frac{1}{b}} + 4be^{\frac{2H}{b}} e^{\frac{2-1}{b}} + c\frac{2}{b} + c\frac$$

In order to have two solutions for the Eq. (20), we need all the factors in brackets in Eq. (20) to be of the same order. Consequently we obtain that $= {}_{b}=(2 {}_{b}^{0} + {}_{b})$ and $a = a^{0} \exp[H = (2 {}_{b}^{0} + {}_{b})]$, where a^{0} b c. The value of a^{0} for which the critical point occurs corresponds to the case where the rescaled equation:

$$0 = a^{0}e^{-\frac{1}{b}} + 4be^{\frac{2-1}{b}} + c\frac{2}{(\frac{b}{b})^{2}}e^{-\frac{1}{b}}$$
(21)

has an unique real solution. For simplicity, we assume that $_{\rm b} = {}^{0}_{\rm b}$, but similar results are found when both correlation lengths are dierent. We refrain to give explicit solutions and we just mention that indeed $a^{0}=c$ 1 and the value of 1 at the critical point is $1_{\rm c}$ $_{\rm b}$ for reasonable values of b and c. Consequently, the interfacial position at the critical point $l_{\rm c}$ H =3 and the NI capillary transition shift ${}^{\rm W1}_{\rm W}$ $_{\rm W}$ exp(H =3 b) and from Eq. (18) exp(2H =3 b).

A num erical com parison of these predictions with our DFT calculations, although it would be very interesting, is extremely dicult due to the limitations of our num erical procedure and it will not be carried out in this work. However, at least qualitatively these predictions have been con med by the DFT calculations even for not so large values of H. B. The case $_{W} > _{W}^{d}$

Now we turn to study the conned system for $_{W} > {}^{d}_{W}$. We ist considered the case $_{W}$ = $_{A}$ = 0:70 and H = 20d. D i erent con ned states are obtained as the chem ical potential increases (see Fig. 7). The rst cases Figs. 7 (a) and 7 (b) clearly correspond to a vapor-like and isotropic-like states, and we will denote them as V and I, respectively. There is in both cases a hom eotropically-anchored nem atic layer close to the substrate at z = 0 and a random planar layer close to the substrate at z = H. As the chem ical potential increases, the random planar layer at z = H undergoes a transition to a planar biaxial state. Again this rst-order transition is a rem in iscence of the I I^N surface transition corresponding to the substrate at z = H, and we will denote both con ned states I and I^{N} by analogy with the sem i-in nite phenom enology. As the chem ical potential is further increased, the nem atic layer increases and a state in which an isotropic and a nem atic layer coexist is obtained (Fig. 7 (c)). There is no phase transition between the isotropic-like $I^{\mathbb{N}}$ and the nem atic-like $\mathbb{N}^{\mathbb{S}}$ states, but a sm ooth transform ation sim ilar to the expected one when both substrates are completely wet by di erent bulk phases at coexistence. Finally, there is a transition to a new nem atic-like state (the L state in Ref. 21, that we will denote as N^L), characterized by an almost linear distorsion from hom eotropic to planar con guration on the tilt angle through the pore, although the intrinsic order parameter takes essentially the bulk value except close to the substrates (see Fig. 7 (d)). This transition between the N $^{\rm L}$ and N $^{\rm S}$ state is rst order and converges to the anchoring transition that is observed in the sem i-in nite case with a substrate that favors a hom extropic anchoring as H ! 1¹⁷. A more detailed discussion about this transition can be found in Ref. 21.

For larger values of H, the capillary N I transition appears as a transition between an I^{N} state and a N^L state for dhem ical potentials smaller than the bulk N I transition value. A s _W approaches $_{W}^{d}$, the range of values of H for which capillary transition does not exist is wider. For $_{W} = _{A} = 0.53$ (close to the dewetting transition point) the capillary N I transition does not appear until H =d > 150. Fig. 8 shows the continuous change of the nem atic layer as the chem ical potential increases for H = 20d, which is analogous to the behavior observed for $_{W} = _{A} = 0.70$. Fig. 9 shows how the curves of the averaged intrinsic order parameter as a function of the chem ical potential change for increasing pore widths. For the narrowest pore (H = 10d), a single transition is observed between an isotropic state to an state with som e nem atic ordering. However, as H is increased, it becom es clear that this transition is again a rem iniscence of the I I^N transition in the sem i-in nite case. The localization of this transition depends weakly on the pore width H. For H > 13d, the N^L N^S transition appears at chem ical potentials larger than the bulk NI coexistence value. This transition does not appear for H = 10d, which is a clear indication of the existence of a critical point for the N^L N^S transition at sm all values of H. As H increases, the chem ical potential value for N^L N^S transition shifts to lower values. Finally, we observe that the U curve becomes increasingly steep at the bulk NI transition as H ! 1. This fact is a consequence of the form ation of interfacial-like states (as Fig. 7 (c)) in the proximities of the bulk NI coexistence chem ical potential.

The non-existence of a capillary NI transition in the situation described above is unexpected. First, the nite-width e ects are much more pronounced for $_{W} > _{W}^{d}$ than below \mathbb{W}^{1} . As a consequence, we observe signi cant departures from the bulk behavior for wider pores and in a larger range of w than when we approach the complete wetting situation from below (i.e. $_{W} < _{W}^{w1}$). This fact suggests the emergence of a new length scale in the system . On the other hand, as the dew etting transition is rst order, we could naively expect that under con nem ent and large enough H the capillary transition disappearance point is shifted to lower values of $_{\rm W}$ ^{4,24} (recall that the role of $_{\rm W}$ or the tem perature is reversed in the dewetting transition with respect to the wetting transition). To understand this situation we recall that the con nement in a hybrid cell distabilizes the N $^{\rm L}$ with respect to the N $^{\rm S}$. A simple phenom enological argument can be used to explain this fact²¹. For large enough values of H, the excess free-energy per surface area of a N^S state is given by the sum of the surface free energies between each substrate and a nem atic uid which is planar-anchored with respect to them. The nite width corrections are expected to decay exponentially. On the other hand, the large H behavior free energy of the N $^{\rm L}$ state is the sum of the surface tensions of the interface between the z = 0 substrate and a hom eotropically-anchored nem atic uid and the corresponding between the planar-anchored nem atic uid and the z = H substrate. For this state the nite-width correction is dom inated by the elastic deform ations contribution and decays as K $_3$ 2 =8H as H $\,$! 1 , where K $_3$ is a Frank-O seen elastic constant²¹. So, for a given temperature, the N^S N^L transition is always shifted towards higher chem ical potentials than the anchoring transition, and the convergence to it for large values of H is quite slow. A lthough this argum ent in plicitely assumes that the

inhom ogeneities are restricted to m icroscopic regions around each substrate, it is also valid if we allow the N^S state to develop an isotropic layer close to the z = 0 substrate (as occurs close to the bulk N I coexistence). Consequently, for $_{W}^{d} < _{W} < _{W}^{m}$ and m oderate values of H, the most stable nem atic-like state close to the bulk N I coexistence is N^S, and therefore there is no capillary transition. A s H increases, the N^L state becomes more stable than the N^S state near the N I bulk transition, and eventually the capillary transition between a I^N state and a N^L occurs.

An interesting feature of the NI capillary transition in this regime is that it is linked to the purely surface transition N^S N^L. As explained before, for small values of H there is no NI capillary transition but if H is not too small there is a N^S N^L transition. As H increases, the chemical potential corresponding to the N^S N^L transition shifts to smaller values, and eventually crosses the value corresponding to the bulk NI transition (see Fig. 10). W hen this happens, the transition is between a isotropic-like I^N state to the nem aticlike N^L state: the capillary NI transition is recovered. Finally, the K elvin relationship Eq. (16) predicts that the capillary transition value of approaches the bulk NI value from below. The DFT results for large H support this prediction. So, at xed temperature and chemical potential, and changing H, reentrance of the isotropic-like state is observed (see Fig. 10).

V. CONCLUSIONS

In this paper we have reported a DFT study of the NI capillary transition under con nement in a slit-pore where each substrate favors a dierent anchoring condition. We found that there is an interplay between the phenomenology found in the semi-in nite problems with the phenomenology which appeared in the con ned problem. We have focussed in the non-existence of the NI capillary transition as a result of both substrates to be wet by dierent phases. If we approach this region from below, we observe a distabilization of the two-phase region with respect to the one-phase region. Moreover, the capillary NI transition nishes in a critical point. These indings are dierent from the ones reported by Q uintana et al²⁴ and this discrepancy can be traced to the dierent order of the wetting transition. When we approach the non-existence range for the NI capillary transition from above, a dierent mechanism is involved in the nite-size elects of the capillary NI transition. A l-

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though the wetting transition which drives the disappearance of the capillary transition is rst-order, the two-phase region is still distabilized with respect to the one-phase region. The explanation for this is the existence of two nem atic-like locally stable phases with a relative stability dependent on the pore width. One of them corresponds to a complete wetting situation, so links with the isotropic-like states without undergoing a phase transition. So, as H increases, the phase transition between two nem atic-like states transform s continuously to the NI capillary transition. As a consequence, a reentrant behavior for the isotropic-like state is observed by varying the pore width and keeping the tem perature and chem ical potential constant.

A lthough we have restricted our study to an isotherm case, we anticipate that we would nd a similar behavior if the temperature is changed instead of the value of $_{W}$. On the other hand, the condition $\frac{1}{W} = \frac{2}{W}$ is not so restrictive as soon as the wetting transition of the z = H wall precedes the complete wetting at the z = 0 wall. If such a condition is not ful led, our conclusions may change.

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FIG.1: The adsorption plotted vs. the chem ical potential for a sem i-in nite geometry where the uid is isotropic in bulk and the substrate favors hom eotropic anchoring. The dashed line corresponds to $_{\rm W} = _{\rm A} = 0.3$ and the continuous line to $_{\rm W} = _{\rm A} = 0.66$. The I I^N transition for the latter case is represented by the dotted line. The insets represent the reduced density

 d^3 and extrinsic order parameter proles , and for dierent chemical potentials and w = A = 0.66.

FIG. 2: Plot of the reduced density d^3 and extrinsic order parameter proles, and for $_{W} = _{A} = 0.70$ and = 3.918, obtained by numerical minimization for R = 435d. Inset: the intrinsic order parameters U and corresponding to the same state. The intrinsic order parameter B is zero except close to z = R (not shown for clarity).

FIG. 3: Plot of the cosine of the contact angle of an isotropic phase droplet on the substratenem atic interface as a function of the uid-substrate interaction strength $_{W}$ (thick continuous line). The led circles correspond to the num erical estimates for $_{W} > _{W}^{W^3}$ (see text for explanation).

FIG. 4: P bt of the averaged intrinsic order parameter throughout the pore U as a function of the reduced chemical potential for $_{W} = _{A} = 0.3$ and H = d = 10 (continuous line) and H = d = 20 (dashed line). The dotted lines show the location of the capillary N I transition. Inset: the diam onds represent our DFT values of the chemical potential for $_{W} = _{A} = 0.3$ at the capillary N I transition for H = d = 10, 20 and 35, and the continuous line is the K elvin law prediction, Eq. (16).

FIG. 5: P bt of the averaged intrinsic order parameter throughout the pore U as a function of the reduced chemical potential for H = d = 20 and $_{W} = _{A} = 0.35$ (dashed line), $_{W} = _{A} = 0.41$ (continuous line) and $_{W} = _{A} = 0.45$ (dot-dashed line). The dotted lines show the location of the I I^N transition (left) and capillary NI transitions (right). Inset: The sym bols are the coexistence values of U at the I I^N and capillary NI transitions for di erent values of $_{W}$. The continuous lines are to guide the eye.

FIG. 6: P lot of the averaged intrinsic order parameter throughout the pore U as a function of the reduced chemical potential for $_{W} = _{A} = 0.465$ and H = d = 10, 20, 40, 50 and 60.

FIG. 7: Plot of the density (d^3) and intrinsic uniaxial order parameter (U) for the uid con ned in a pore of width H = 20d and $_W = _A = 0.70$ and chem ical potentials: (a) = 4:7, (b) = 4:45, (c) = 3:95 and = 3:7.

FIG.8: Density (d^3) and intrinsic uniaxial order parameter prodes (U) for H = 20d and $_W = _A = 0.53$. The chemical potentials run from = 4.03 to = 3.64 with a step of () = 0.01.

FIG. 9: P bt of the averaged intrinsic order parameter U throughout the pore vs the reduced chem ical potential for $_{\rm W} = _{\rm A} = 0.53$ and H =d = 10, 13, 20, 30, 40 and 80. The discontinuities of U () correspond to the I I^N (left) and N^S N^L (right) transitions.

FIG.10: Plot of the reduced chem ical potential corresponding to the N^S N^L transition (or the N I capillary transition, see text for explanation) as a function of the reduced inverse pore width d=H for values of $_{W} = _{A} = 0.49$ (circles), 0.53 (diam onds), 0.60 (triangles up) and 0.66 (triangles down). The continuous lines are only to guide the eye.



I.RODRIGUEZ-PONCE et al, FIGURE 1



I.RODRIGUEZ-PONCE et al, FIGURE 2



I.RODRIGUEZ-PONCE et al, FIGURE 3



I.RODRIGUEZ-PONCE et al, FIGURE 4



I.RODRIGUEZ-PONCE et al, FIGURE 5



I.RODRIGUEZ-PONCE et al, FIGURE 6



I.RODRIGUEZ-PONCE et al, FIGURE 7



I.RODRIGUEZ-PONCE et al, FIGURE 8



I.RODRIGUEZ-PONCE et al, FIGURE 9



I.RODRIGUEZ-PONCE et al, FIGURE 10